

Description

The AOD4132-HXY uses advanced trench technology

to provide excellent R_{DS(ON)}, low gate charge and

operation with gate voltages as low as 4.5V. This

device is suitable for use as a

Battery protection or in other Switching application.

General Features

 $V_{DS} = 30V I_{D} = 100 A$

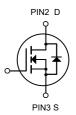
 $R_{DS(ON)} < 5m\Omega$ @ $V_{GS}=10V$

Application

Battery protection

Load switch

Uninterruptible power supply



TO-252-2L (TO-252-2(DPAK))

N-Channel MOSFET

Package Marking and Ordering Information

Product ID	Pack	Marking	Qty(PCS)
AOD4132-HXY	TO-252-2L(TO-252-2(DPAK))	100N03DXXX YYYY	2500

Absolute Maximum Ratings (T_c=25℃ unless otherwise noted)

Symbol	Parameter	Rating		Units
VDS	Drain- Source Voltage	30		V
VGS	Gate-Source Voltage	±20		V
I _D @T _C =25°C	Continuous Drain Current, V _{GS} @ 10V ¹	100		Α
I _D @T _C =100°C	Continuous Drain Current, V _{GS} @ 10V ¹	57		А
I _D @T _A =25°C	Continuous Drain Current, V _{GS} @ 10V ¹	27	17	А
I _D @T _A =70°C	Continuous Drain Current, V _{GS} @ 10V ¹	23	14.5	А
Ірм	Pulsed Drain Current ²	160		Α
EAS	Single Pulse Avalanche Energy ³	115.2		mJ
las	Avalanche Current	48		Α
P _D @T _C =25°C	Total Power Dissipation ⁴	53		W
P _D @T _A =25°C	Total Power Dissipation ⁴	6	2.4	W
Тѕтс	Storage Temperature Range	-55 to 175		°C
TJ	Operating Junction Temperature Range	-55 to 175		°C
R _θ JA	Thermal Resistance Junction-ambient (Steady State) ¹	62		°C/W
R _θ JA	Thermal Resistance Junction-Ambient ¹ (t ≤10s)	25		°C/W
Reuc	Thermal Resistance Junction-Case ¹	2.8		°C/W



Electrical Characteristics (T_J=25°C, unless otherwise noted)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
BVpss	Drain-Source Breakdown Voltage	V _{GS} =0V , I _D =250uA	30			V
△BVɒss/△Tɹ	BVDSS Temperature Coefficient	•		0.028		V/°C
.Rds(on)		V _{GS} =10V , I _D =30A		3.8	5.5	
.TADS(UN)	Static Drain-Source On- Resistance ²	V _{GS} =4.5V , I _D =15A		7.5	9	mΩ
V _G S(th)	Gate Threshold Voltage	V _{GS} =V _{DS} , I _D =250uA	1.0	1.5	2.5	V
$\triangle V_{GS(th)}$	V _{GS(th)} Temperature Coefficient			-6.16		mV/°C
		V _{DS} =24V , V _{GS} =0V ,			1	
IDSS	Drain-Source Leakage Current	T _J =25°C V _{DS} =24V , V _{GS} =0V , T _J =55°C			5	uA
Igss	Gate-Source Leakage Current	V_{GS} = $\pm 20V$, V_{DS} = $0V$			±100	nA
gfs	Forward Transconductance	V _{DS} =5V , I _D =30A		22		S
R _g	Gate Resistance	Gate Resistance V _{DS} =0V , V _{GS} =0V , f=1MHz		1.7	3.4	Ω
Qg	Total Gate Charge (4.5V)			20		nC
Q _{gs}	Gate-Source Charge	V _{DS} =15V , V _{GS} =4.5V , I _D =15A		7.6		
Q _{gd}	Gate-Drain Charge			7.2		
T _{d(on)}	Turn-On Delay Time			7.8		ns
Tr	Rise Time	V _{DD} =15V , V _{GS} =10V ,		15		
T _d (off)	Turn-Off Delay Time	-R _G =3.3 -I _D =15A		37.3		
T _f	Fall Time	-1D-13A		10.6		
C _{iss}	Input Capacitance			2295		
Coss	Output Capacitance	V _{DS} =15V , V _{GS} =0V , f=1MHz		267		pF
Crss	Reverse Transfer Capacitance	11- 11VII 12		210		
Is	Continuous Source Current ^{1,5}	V _G =V _D =0V , Force			80	Α
Ism	Pulsed Source Current ^{2,5}	Current			160	Α
Vsp	Diode Forward Voltage ²	iode Forward Voltage ² V _{GS} =0V , I _S =1A , T _J =25°C			1	V
t _{rr}	Reverse Recovery Time	IF=30A , dI/dt=100A/μs ,		14		nS
Qrr	Reverse Recovery Charge	T _J =25°C		5		nC

Note:

^{1.}The data tested by surface mounted on a 1 inch² FR-4 board with 2OZ copper.

^{2.}The data tested by pulsed , pulse width .The EAS data shows Max. rating .

^{3.} The test cond $\!\leq$ 300us , duty cycle ition is V_DD=25 $\!\leq$ V,V 2%GS =10V,L=0.1mH,I_AS=53.8A

^{4.}The power dissipation is limited by 175°C junction temperature

^{5.}The data is theoretically the same as ID and IDM, in real applications, should be limited by total power dissipation.



Typical Characteristics

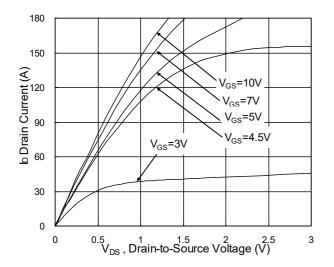


Fig.1 Typical Output Characteristics

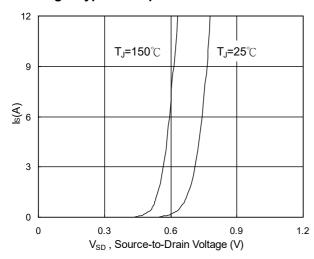


Fig.3 Forward Characteristics of Reverse

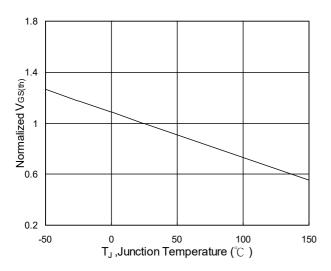


Fig.5 Normalized $V_{\text{GS(th)}}$ vs. T_{J}

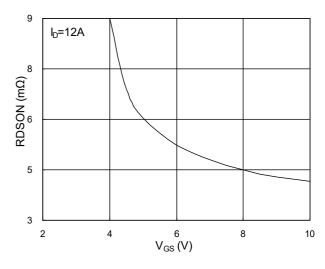


Fig.2 On-Resistance vs. G-S Voltage

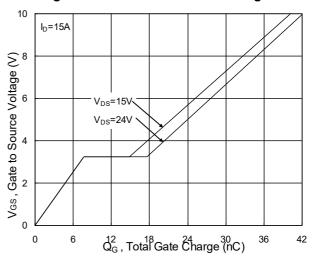


Fig.4 Gate-Charge Characteristics

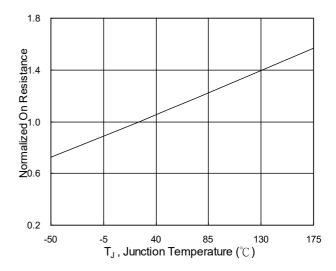
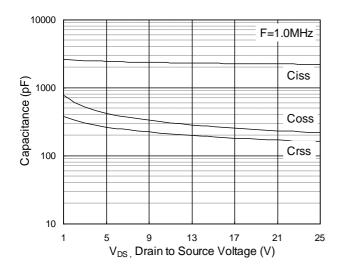


Fig.6 Normalized R_{DSON} vs. T_J





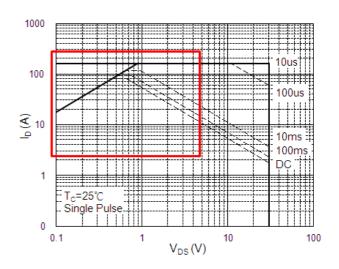


Fig.7 Capacitance

Fig.8 Safe Operating Area

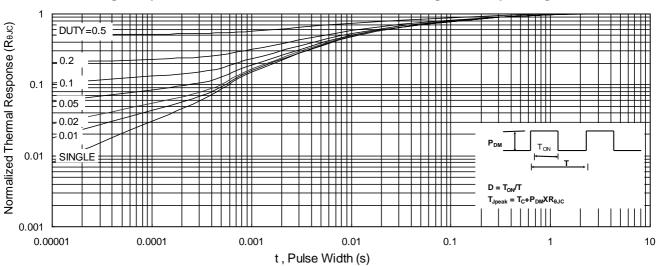


Fig.9 Normalized Maximum Transient Thermal Impedance

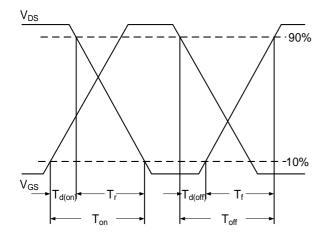


Fig.10 Switching Time Waveform

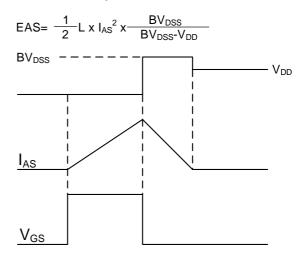
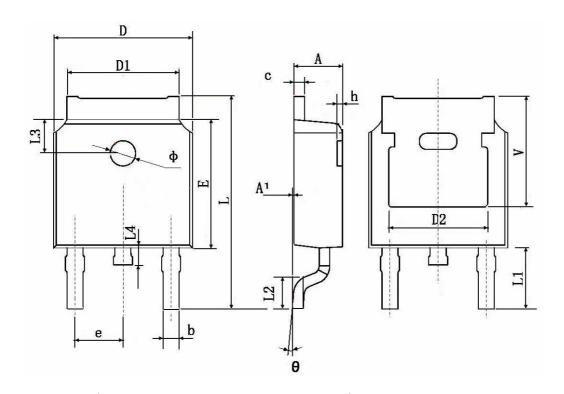


Fig.11 Unclamped Inductive Switching Waveform



TO-252-2L(TO-252-2(DPAK)) Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min.	Max.	Min.	Max.	
А	2.200	2.400	0.087	0.094	
A1	0.000	0.127	0.000	0.005	
b	0.660	0.860	0.026	0.034	
С	0.460	0.580	0.018	0.023	
D	6.500	6.700	0.256	0.264	
D1	5.100	5.460	0.201	0.215	
D2	0.483 TYP.		0.190 TYP.		
Е	6.000	6.200	0.236	0.244	
е	2.186	2.386	0.086	0.094	
L	9.800	10.400	0.386	0.409	
L1	2.900	2.900 TYP.		TYP.	
L2	1.400	1.700	0.055	0.067	
L3	1.600 TYP.		0.063 TYP.		
L4	0.600	1.000	0.024	0.039	
Ф	1.100	1.300	0.043	0.051	
θ	0°	8°	0°	8°	
h	0.000	0.300	0.000	0.012	
V	5.350 TYP.		0.211 TYP.		



Attention

- Any and all HUA XUAN YANG ELECTRONICS products described or contained herein do not have specifications that can handle applications that require extremely high levels of reliability, such as life-support systems, aircraft's control systems, or other applications whose failure can be reasonably expected to result in serious physical and/or material damage. Consult with your HUA XUAN YANG ELECTRONICS representative nearest you before using any HUA XUAN YANG ELECTRONICS products described or contained herein in such applications.
- HUA XUAN YANG ELECTRONICS assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all HUA XUAN YANG ELECTRONICS products described or contained herein.
- Specifications of any and all HUA XUAN YANG ELECTRONICS products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.
- HUA XUAN YANG ELECTRONICS CO.,LTD. strives to supply high-quality high-reliability products. However, any and all semiconductor products fail with some probability. It is possible that these probabilistic failures could give rise to accidents or events that could endanger human lives, that could give rise to smoke or fire, or that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.
- In the event that any or all HUA XUAN YANG ELECTRONICS products(including technical data, services) described or contained herein are controlled under any of applicable local export control laws and regulations, such products must not be exported without obtaining the export license from the authorities concerned in accordance with the above law.
- No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written permission of HUA XUAN YANG ELECTRONICS CO.,LTD.
- Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production.

 HUA XUAN YANG ELECTRONICS believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.
- Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. When designing equipment, refer to the "Delivery Specification" for the HUA XUAN YANG ELECTRONICS product that you intend to use.